

PART NUMBER

MM88C29N-ROCV

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

• Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing. FAIRCHILD

SEMICONDUCTOR TM

October 1987 Revised June 2001

MM88C29 • MM88C30 Quad Single-Ended Line Driver • Dual Differential Line Driver

General Description

The MM88C30 is a dual differential line driver that also performs the dual four-input NAND or dual four-input AND function. The absence of a clamp diode to $V_{\rm CC}$ in the input protection circuitry of the MM88C30 allows a CMOS user to interface systems operating at different voltage levels. Thus, a CMOS digital signal source can operate at a $V_{\rm CC}$ voltage greater than the $V_{\rm CC}$ voltage of the MM88C30 line driver. The differential output of the MM88C30 eliminates ground-loop errors.

The MM88C29 is a non-inverting single-wire transmission line driver. Since the output ON resistance is a low 20Ω typ., the device can be used to drive lamps, relays, solenoids, and clock lines, besides driving data lines.

Features

- Wide supply voltage range: 3V to 15V
- High noise immunity: 0.45 V_{CC} (typ.)
- Low output ON resistance: 20Ω (typ.)

Ordering Code:

Order Number	Package Number	Package Description		
MM88C29N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide		
MM88C30M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow		
MM88C30N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide		
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.				

Connection Diagrams







2

Absolute Maximum Ratings(Note 1)

Voltage at Any Pin (Note 2)	–0.3V to V _{CC} +16V
Operating Temperature Range	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V _{CC} Range	3V to 15V
Absolute Maximum V _{CC}	18V

		-
Average Current at Output		MM
MM88C30	50 mA	88
MM88C29	25 mA	õ
Maximum Junction Temperature, T _j	150°C	29
Lead Temperature		•
(Soldering, 10 seconds)	260°C	\leq
		8≥
Note 1: "Absolute Maximum Ratings" are those values bey	ond which the	80
safety of the device cannot be guaranteed. Except for "Operative Range" they are not meant to imply that the devices s	ating Tempera- hould be oper-	8
ated at these limits. The Electrical Characteristics tables pro	vide conditions	ö

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Tempera-ture Range" they are not meant to imply that the devices should be oper-ated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

Note 2: AC Parameters are guaranteed by DC correlated testing.

DC Electrical Characteristics

Min/Max lii	mits apply across temperature rang	e unless otherwise noted				
Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO 0	MOS			•		
V _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 5V$	3.5			V
		$V_{CC} = 10V$	8			V
V _{IN(0)}	Logical "0" Input Voltage	$V_{CC} = 5V$			1.5	V
		$V_{CC} = 10V$			2	V
I _{IN(1)}	Logical "1" Input Current	$V_{CC} = 15V, V_{IN} = 15V$		0.005	1	μΑ
I _{IN(0)}	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1	-0.005		μA
I _{CC}	Supply Current	$V_{CC} = 5V$		0.05	100	mA
OUTPUT D	RIVE					
ISOURCE	Output Source Current	$V_{OUT} = V_{CC} - 1.6V,$				
		$V_{CC} \ge 4.75V$, $T_i = 25^{\circ}C$	-47	-80	mA	
		$T_j = 85^{\circ}C$	-32	-60		mA
	MM88C29	$V_{OUT} = V_{CC} - 0.8V$	-2	-20		mA
	MM88C30	$V_{CC} \ge 4.5V$				
I _{SINK}	Output Sink Current	$V_{OUT} = 0.4V, V_{CC} = 4.75V,$				
		$T_j = 25^{\circ}C$	9.5	22		mA
		$T_j = 85^{\circ}C$	8	18		mA
		$V_{OUT} = 0.4V, V_{CC} = 10V,$				
		$T_j = 25^{\circ}C$	19	40		mA
		$T_j = 125^{\circ}C$	15.5	33		mA
ISOURCE	Output Source Resistance	$V_{OUT} = V_{CC} - 1.6V,$				
		$V_{CC} \ge 4.75V$, $T_i = 25^{\circ}C$		20	34	Ω
		T _i = 85°C		27	50	Ω
I _{SINK} Out	Output Sink Resistance	$V_{OUT} = 0.4V, V_{CC} = 4.75V,$				
		$T_j = 25^{\circ}C$		18	41	Ω
		$T_j = 85^{\circ}C$		22	50	Ω
		$V_{OUT} = 0.4V, V_{CC} = 10V,$				
		$T_i = 25^{\circ}C$		10	21	Ω
		T _i = 85°C		12	26	Ω
	Output Resistance					
	Temperature Coefficient					
	Source			0.55		%/°C
	Sink			0.40		%/°C
θ_{JA}	Thermal Resistance			150		°C/W
	(N-Package)					
	1	•	1			

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{pd}	Propagation Delay Time to					
	Logical "1" or "0"	(See Figure 1)				
	MM88C29	$V_{CC} = 5V$		80	200	n
		$V_{CC} = 10V$		35	100	n
	MM88C30	$V_{CC} = 5V$		110	350	n
		$V_{CC} = 10V$		50	150	n
t _{pd}	Differential Propagation Delay	$R_L = 100\Omega, \ C_L = 5000 \ pF$				
	Time to Logical "1" or "0"	(See Figure 2)				
	MM88C30	$V_{CC} = 5V$			400	n
		$V_{CC} = 10V$			150	n
CIN	Input Capacitance					
	MM88C29	(Note 3)		5.0		р
	MM88C30	(Note 3)		5.0		р
C _{PD}	Power Dissipation Capacitance					
	MM88C29	(Note 3)		150		р
	MM88C30	(Note 3)		200		n

Note 3: Capacitance is guaranteed by periodic testing.

Note 4: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics application note AN-90 (CMOS Logic Databook).







6



